

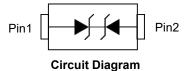
# Product data sheet

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# MSESD5Z5CL

Semiconductor Compiance





SOD-523

#### Feature

80W peak pulse power per line (t\_P = 8/20  $\mu s)$ 

SOD-523 package

Replacement for MLV(0603)

Bidirectional configurations

Protects one power or I/O port

Low clamping voltage

RoHS compliant

Transient protection for data lines to IEC 61000-4-2(ESD) ±30kV(air), ±30kV(contact); IEC 61000-4-4 (EFT) 40A (5/50ns)

#### **Applications**

Cellular phones

Portable devices

Digital cameras

Power supplies

#### **Mechanical Characteristics**

Lead finish:100% matte Sn(Tin)

Mounting position: Any

Qualified max reflow temperature:260°C Device meets MSL 1 requirements Pure tin plating: 7 ~ 17 um

Pin flatness: ≤3mil

#### Electrical characteristics per line@25°C( unless otherwisespecified)

| Parameter                        | Symbol           | Conditions                        | Min. | Тур. | Max. | Unit |
|----------------------------------|------------------|-----------------------------------|------|------|------|------|
| Peak Reverse Working Voltage     | V <sub>RWM</sub> |                                   |      |      | 5    | V    |
| Breakdown Voltage                | $V_{BR}$         | I⊤ = 1mA                          | 5.8  |      | 7.8  | V    |
| Reverse Leakage Current          | I <sub>R</sub>   | V <sub>RWM</sub> = 5V T=25°C      |      |      | 1.0  | μA   |
| Clamping Voltage <sup>1)</sup>   | V <sub>C</sub>   | TLP = 16A, t <sub>p</sub> = 100ns |      | 9.0  |      | V    |
| Dynamic resistance <sup>1)</sup> | R <sub>DYN</sub> |                                   |      | 0.15 |      | Ω    |
| Clamping Voltage <sup>2)</sup>   | Vc               | IPP=10A                           |      | 8    | 10   | V    |
| Junction Capacitance             | CJ               | V <sub>R</sub> =0V f = 1MHz       |      | 33   |      | pF   |

Notes:

1.TLP parameter:  $Z_0=50\Omega$ ,  $t_p=100$ ns,  $t_r=2$ ns, averaging window from 60ns to 80ns. R<sub>DYN</sub> is calculated from 4A to 16A.

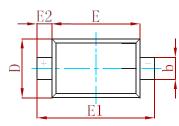
2.Non-repetitive current pulse, according to IEC61000-4-5.

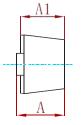
| Rating                                    | Symbol           | Value       | Unit |
|---|------------------|-------------|------|
| Peak Pulse Power (t <sub>p</sub> =8/20µs) | P <sub>pp</sub>  | 80          | W    |
| Operating Temperature                     | TJ               | -55 to +150 | °C   |
| Storage Temperature                       | T <sub>STG</sub> | -55 to +150 | °C   |

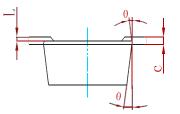
#### Absolute maximum rating@25°C



### PACKAGE MECHANICAL DATA

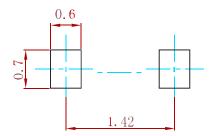






| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |  |
|--------|---------------------------|-------|----------------------|-------|--|
|        | Min                       | Max   | Min                  | Max   |  |
| A      | 0.510                     | 0.770 | 0.020                | 0.031 |  |
| A1     | 0.500                     | 0.700 | 0.020                | 0.028 |  |
| b      | 0.250                     | 0.350 | 0.010                | 0.014 |  |
| С      | 0.080                     | 0.150 | 0.003                | 0.006 |  |
| D      | 0.750                     | 0.850 | 0.030                | 0.033 |  |
| E      | 1.100                     | 1.300 | 0.043                | 0.051 |  |
| E1     | 1.500                     | 1.700 | 0.059                | 0.067 |  |
| E2     | 0.200 REF                 |       | 0.008 REF            |       |  |
| L      | 0.010                     | 0.070 | 0.001                | 0.003 |  |
| 0      | 7° REF                    |       | 7° REF               |       |  |

## Suggested Pad Layout



Note:

1.Controlling dimension:in millimeters.

2.General tolerance:±0.05mm.

3. The pad layout is for reference purposes only.

#### **REEL SPECIFICATION**

| P/N        | PKG     | QTY  |
|------------|---------|------|
| MSESD5Z5CL | SOD-523 | 3000 |



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